



N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	6mΩ @ V _{GS} = 10V	65A
30V	9.8mΩ @ V _{GS} = 4.5V	55A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

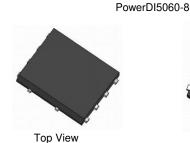
- Backlighting
- Power Management Functions
- DC-DC Converters

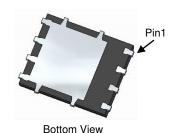
Features and Benefits

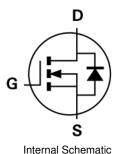
- Low R_{DS(ON)} Minimizes On-State Losses
- Excellent Q_{gd} x R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- 100% Unclamped Inductive Switching Ensures More Reliability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

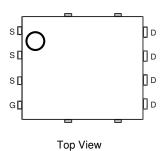
Mechanical Data

- Case: PowerDI[®] 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.097 grams (Approximate)









Pin Configuration

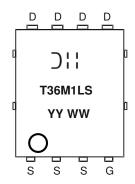
Ordering Information (Note 4)

Part Number		Case	Packaging	
DMT36M1LPS-13		PowerDI5060-8	2,500/Tape & Reel	

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



T36M1LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 17 = 2017)
WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_A = +25$ °C $T_A = +70$ °C	I _D	16 12	Α
Continuous Drain Current, $V_{GS} = 10V$ (Note 7) $ T_C = +25^{\circ}C $ $ T_C = +70^{\circ}C $		I _D	65 50	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	100	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	3	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle	I _{SM}	100	Α	
Avalanche Current, L = 0.1mH (Note 8)	I _{AS}	25	Α	
Avalanche Energy, L = 0.1mH (Note 8)	Eas	31	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	1.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	99	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	P _D	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	50	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	P _D	42	W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	3	°C/W
Operating and Storage Temperature Range		$T_{J_{I}}T_{STG}$	-55 to +150	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

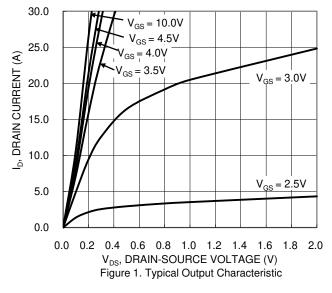
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = 20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	$V_{GS(TH)}$	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	4.8	6	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-nesistance	R _{DS(ON)}	_	6.8	9.8	11122	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V_{SD}	_	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 2A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{ISS}	_	1,155	_	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	456	_			
Reverse Transfer Capacitance	C _{RSS}	_	72	_			
Gate Resistance	Rq	_	1.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Q _G	_	16.7	_			
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}	_	8.4	_		V _{DD} = 15V, I _D = 9A	
Gate-Source Charge	Q _{GS}	_	2.2	_	nC		
Gate-Drain Charge	Q_{GD}	_	3.5	_			
Turn-On Delay Time	t _{D(ON)}	_	3.5	_			
Turn-On Rise Time	t _R	_	5.5	_		$\begin{split} V_{DD} &= 15 V, V_{GS} = 10 V, \\ R_g &= 3 \Omega, I_D = 9 A \end{split}$	
Turn-Off Delay Time	t _{D(OFF)}	-	13.5	_	ns		
Turn-Off Fall Time	t _F	_	4.6	_			
Reverse Recovery Time	t _{RR}	-	19.3	_	ns		
Reverse Recovery Charge	Q _{RR}	_	8.6	_	nC	$I_F = 1.5A$, di/dt = 100A/ μ s	

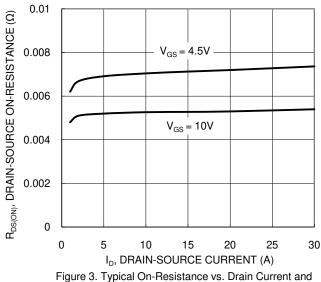
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).

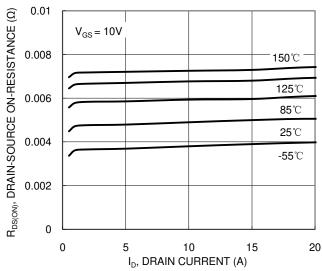
I. Is and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

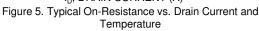


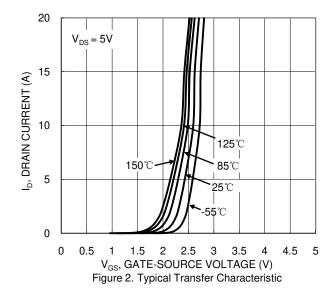


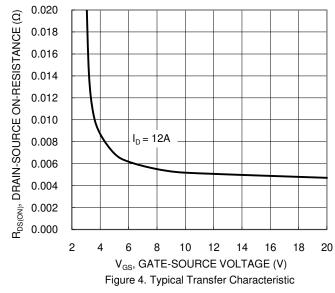


Gate Voltage









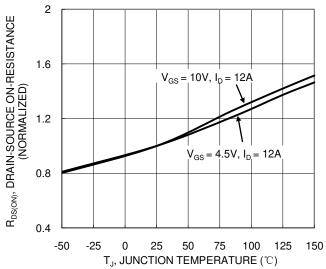
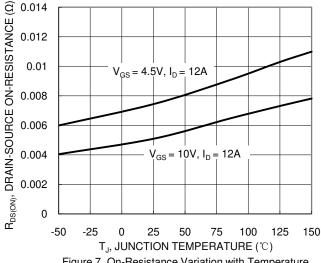
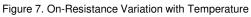
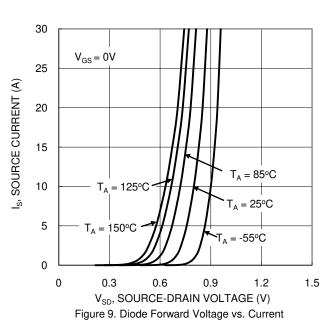


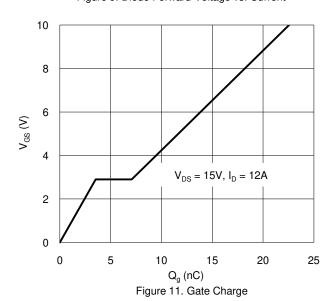
Figure 6. On-Resistance Variation with Temperature











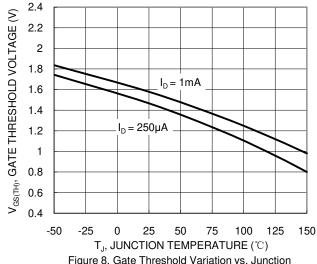
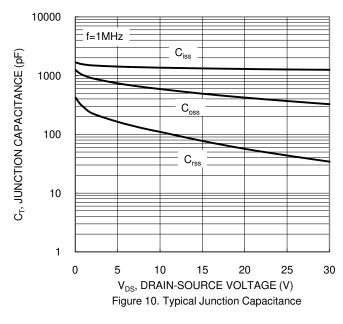
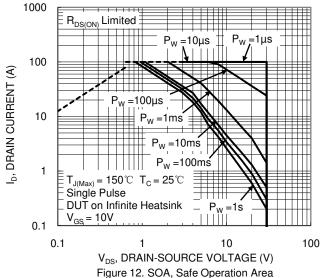
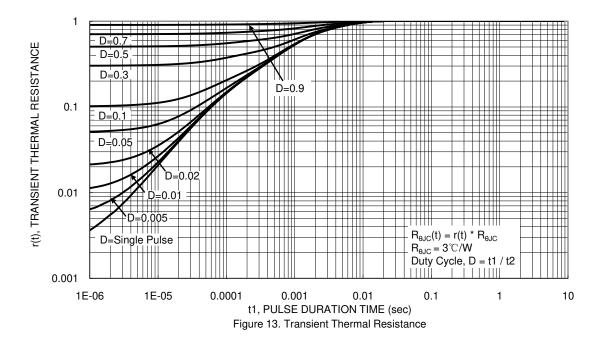


Figure 8. Gate Threshold Variation vs. Junction Temperature







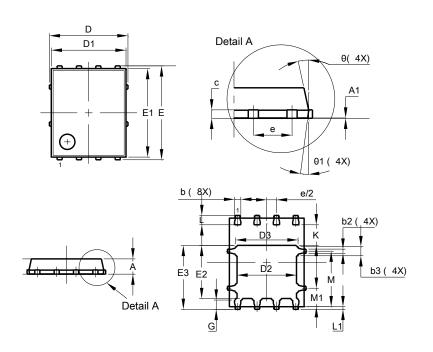




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

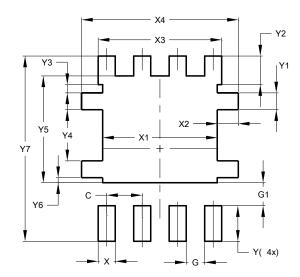


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90 4.30 4.10				
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	_	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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